

SPI20N65C3

Data Sheet

N-Channel MOSFETs (>500V...900V); Package: PG-TO262-3; VDS (max): 650.0 V; Package: I2PAK (TO-262); RDS(ON) @ TJ=25°C VGS=10: 190.0 mOhm; ID(max) @ TC=25°C: 20.7 A; IDpuls (max): 62.1 A;,MOSFET COOL MOS N-CH 650V 20.7A

Manufacturers	Infineon Technologies Corporation
Package/Case	TO-262
Product Type	Transistors
RoHS	Rohs
Lifecycle	



Images are for reference only

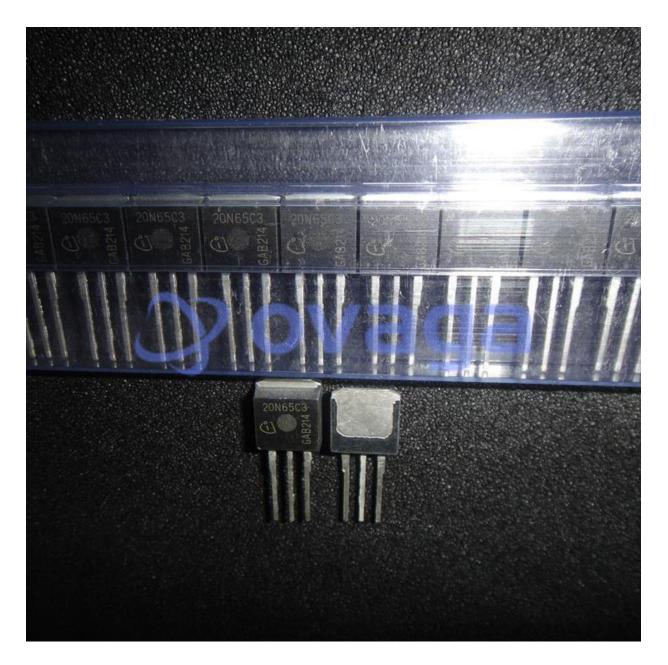
Please submit RFQ for SPI20N65C3 or Email to us: sales@ovaga.com We will contact you in 12 hours.

<u>RFQ</u>

General Description

Ovaga has a large stock of SPI20N65C3 Transistors from Infineon Technologies Corporation and we guarantee that they are original, brand new parts sourced directly from Infineon Technologies Corporation We can provide quality testing reports for SPI20N65C3 upon your request. To obtain a quote, simply fill in the required quantity, contact name, and email address in the quick quote form on the right. Our sales representative will contact you within 12 hours.





Related Products



BSP613P

Infineon Technologies Corporation SOT-223

<u>SPP07N65C3</u>

Infineon Technologies Corporation TO-220AB



SPP11N60C3XKSA1

Infineon Technologies Corporation PG-TO220







SPP11N65C3

Infineon Technologies Corporation TO-220

SPP07N60S5

Infineon Technologies Corporation P-TO220-3-1

IRF640NSPBF

Infineon Technologies Corporation PAK-3



SPD03N60S5

Infineon Technologies Corporation

TO-252



SPP20N60CFD

Infineon Technologies Corporation TO-220AB